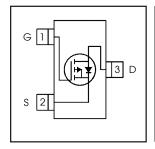
International Rectifier

IRLML9301TRPbF

HEXFET® Power MOSFET

V _{DS}	-30	V
V _{GS Max}	± 20	V
$R_{DS(on) max}$ (@V _{GS} = -10V)	64	$\mathbf{m}\Omega$
$R_{DS(on) max}$ (@V _{GS} = -4.5V)	103	$\mathbf{m}\Omega$





Application(s)

• System/Load Switch

Features and Benefits

Features

Low $R_{DS(on)}$ ($\leq 64m\Omega$)
Industry-standard pinout
Compatible with existing Surface Mount Techniques
RoHS compliant containing no lead, no bromide and no halogen
MSL1, Consumer qualification

Benefits

Lower switching losses
Multi-vendor compatibility
Easier manufacturing
Environmentally friendly
Increased reliability

	results in
logen	\Rightarrow

Symbol	Parameter	Max.	Units
V _{DS}	Drain-Source Voltage	-30	V
$I_D @ T_A = 25^{\circ}C$	Continuous Drain Current, V _{GS} @ 10V	-3.6	
I _D @ T _A = 70°C	Continuous Drain Current, V _{GS} @ 10V	-2.9	Α
I _{DM}	Pulsed Drain Current	-15	
P _D @T _A = 25°C	Maximum Power Dissipation	1.3	W
P _D @T _A = 70°C	Maximum Power Dissipation	0.8	VV
	Linear Derating Factor	0.01	W/°C
V _{GS}	Gate-to-Source Voltage	± 20	V
T_{J}, T_{STG}	Junction and Storage Temperature Range	-55 to + 150	°C

Thermal Resistance

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JA}$	Junction-to-Ambient ③		100	°C/W
R _{eJA}	Junction-to-Ambient (t<10s) ®		99	C/VV

ORDERING INFORMATION:

See detailed ordering and shipping information on the last page of this data sheet.

Notes ① through ④ are on page 10 www.irf.com

Electric Characteristics @ T_J = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions
V _{(BR)DSS}	Drain-to-Source Breakdown Voltage	-30			٧	$V_{GS} = 0V, I_D = -250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_J$	Breakdown Voltage Temp. Coefficient		0.02		V/°C	Reference to 25°C, I _D = -1mA
В	Static Drain-to-Source On-Resistance		51	64	0	V _{GS} = -10V, I _D = -3.6A ②
R _{DS(on)}	Static Drain-to-Source On-Resistance		82	103	mΩ	$V_{GS} = -4.5V, I_D = -2.9A$ ②
$V_{GS(th)}$	Gate Threshold Voltage	-1.3		-2.4	V	$V_{DS} = V_{GS}, I_D = -10\mu A$
I _{DSS}	Drain-to-Source Leakage Current			1		V_{DS} =-24V, V_{GS} = 0V
	Diam-to-Source Leakage Current			150	μA	$V_{DS} = -24V, V_{GS} = 0V, T_{J} = 125^{\circ}C$
I _{GSS}	Gate-to-Source Forward Leakage			-100	nA	$V_{GS} = -20V$
	Gate-to-Source Reverse Leakage			100	IIA	$V_{GS} = 20V$
R _G	Internal Gate Resistance		12		Ω	
gfs	Forward Transconductance	5.0			S	$V_{DS} = -10V, I_{D} = -3.6A$
Q_g	Total Gate Charge	_	4.8			$I_D = -3.6A$
Q_{gs}	Gate-to-Source Charge		1.2		nC	V _{DS} =-15V
Q_{gd}	Gate-to-Drain ("Miller") Charge		2.5			V _{GS} = -4.5V ②
t _{d(on)}	Turn-On Delay Time		9.6			V _{DD} =-15V②
t _r	Rise Time		19		ns	I _D = -1A
t _{d(off)}	Turn-Off Delay Time		16		115	$R_G = 6.8\Omega$
t _f	Fall Time		15			$V_{GS} = -4.5V$
C _{iss}	Input Capacitance		388			V _{GS} = 0V
C _{oss}	Output Capacitance		93		pF	$V_{DS} = -25V$
C _{rss}	Reverse Transfer Capacitance		65			f = 1.0KHz

Source - Drain Ratings and Characteristics

Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions
I _S	Continuous Source Current (Body Diode)			-1.3		MOSFET symbol showing the
I _{SM}	Pulsed Source Current (Body Diode) ①			-15		integral reverse p-n junction diode.
V _{SD}	Diode Forward Voltage			-1.2	٧	$T_J = 25^{\circ}C$, $I_S = -1.3A$, $V_{GS} = 0V$ ②
t _{rr}	Reverse Recovery Time		14	21	ns	$T_J = 25^{\circ}C$, $V_R = -24V$, $I_F = -1.3A$
Q _{rr}	Reverse Recovery Charge		7.2	11	nC	di/dt = 100A/µs ②

International TOR Rectifier

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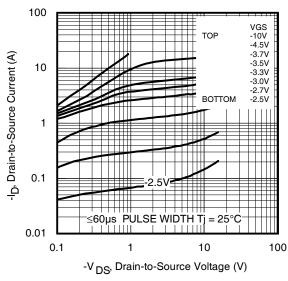


Fig 1. Typical Output Characteristics

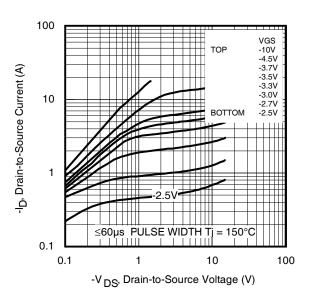


Fig 2. Typical Output Characteristics

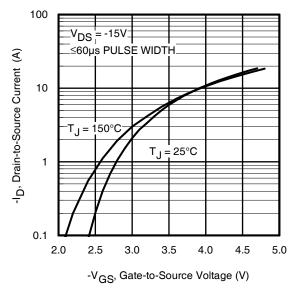


Fig 3. Typical Transfer Characteristics

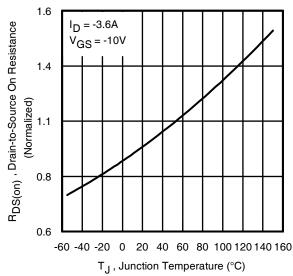


Fig 4. Normalized On-Resistance Vs. Temperature

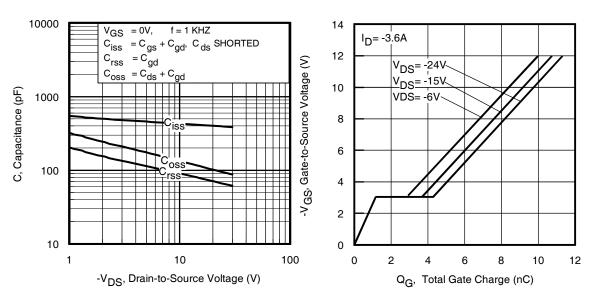


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

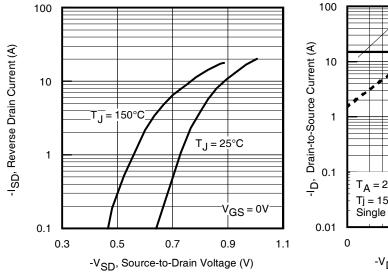


Fig 7. Typical Source-Drain Diode Forward Voltage

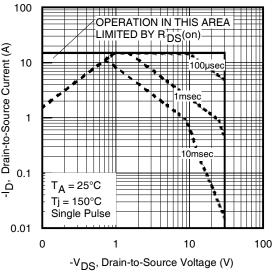


Fig 8. Maximum Safe Operating Area

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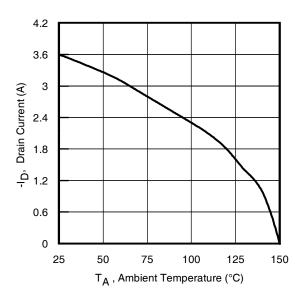


Fig 9. Maximum Drain Current Vs. Ambient Temperature

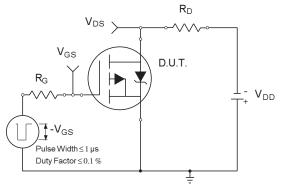


Fig 10a. Switching Time Test Circuit

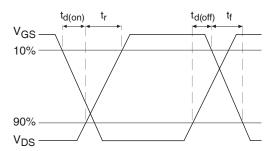


Fig 10b. Switching Time Waveforms

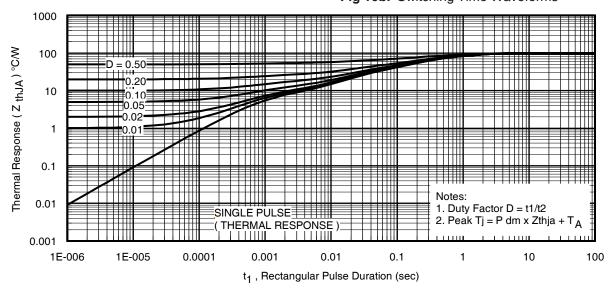
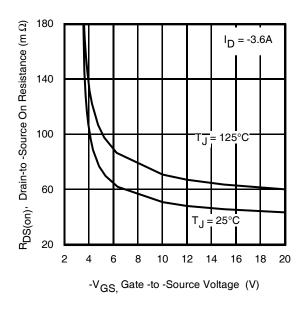


Fig 11. Typical Effective Transient Thermal Impedance, Junction-to-Ambient

International

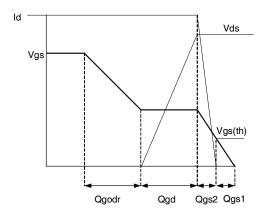
TOR Rectifier



500 $R_{\mbox{\footnotesize{DS}}}(\mbox{\scriptsize{on}}), \mbox{ Drain-to -Source On Resistance } (m\Omega)$ 400 300 200 Vgs = -10V100 0 5 10 20 25 35 15 30 -I_D, Drain Current (A)

Fig 12. Typical On-Resistance Vs. Gate Voltage

Fig 13. Typical On-Resistance Vs. Drain Current



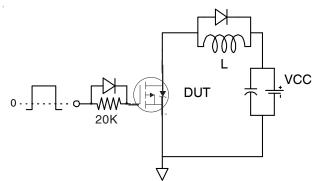


Fig 14a. Gate Charge Waveform

Fig 14b. Gate Charge Test Circuit

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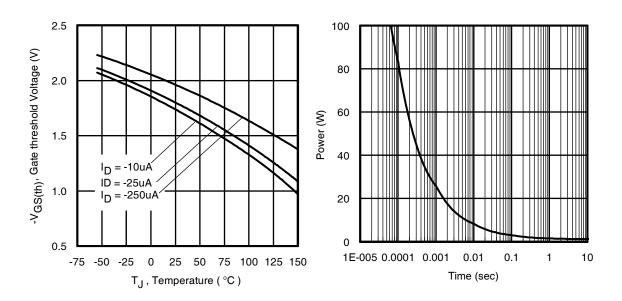


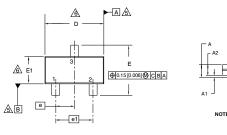
Fig 15. Typical Threshold Voltage Vs. Junction Temperature

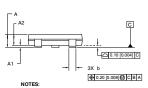
Fig 16. Typical Power Vs. Time

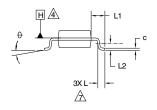


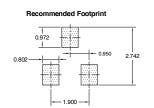
Micro3 (SOT-23) Package Outline

Dimensions are shown in millimeters (inches)









DIMENSIONS						
SYMBOL	MILLIM	ETERS	INCHES			
STIVIDOL	MIN	MAX	MIN	MAX		
Α	0.89	1.12	0.035	0.044		
A1	0.01	0.10	0.0004	0.004		
A2	0.88	1.02	0.035	0.040		
b	0.30	0.50	0.012	0.020		
С	0.08	0.20	0.003	0.008		
D	2.80	3.04	0.110	0.120		
E	2.10	2.64	0.083	0.104		
E1	1.20	1.40	0.047	0.055		
е	0.95	BSC	0.037	BSC		
e1	1.90	BSC	0.075	BSC		
L	0.40	0.60	0.016	0.024		
L1	0.54	REF	0.021	REF		
L2	0.25	BSC	0.010	BSC		
0	0	8	0	8		

- 1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1994
- 2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES]. 3. CONTROLLING DIMENSION: MILLIMETER.
- A CONTROLLING DIMENSION MILLIMETER.

 ADATUM PLANE HIS LOCATED AT THE MOLD PARTING LINE.

 ADATUM AND B TO BE DETERMINED AT DATUM PLANE H.

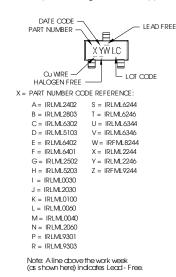
 ADMENSIONS D AND E1 ARE MEASUPED AT DATUM PLANE H. DIMENSIONS DOES NOT INCLIDE MOLD PROTRUSIONS OR INTERLEAD FLASH SHALL NOT EXCEED 0.25 MM [0.010 INCH] PER SIDE.

 ADMENSION LIS THE LEAD LEWISH FOR SOLDEFINIO TO A SUBSTRATE.

 8. OUTLINE CONFORMS TO JEDEC OUTLINE TO 228 AB.

Micro3 (SOT-23/TO-236AB) Part Marking Information

Notes: This part marking information applies to devices produced after 02/26/2001



DATE CODE MARKING INSTRUCTIONS WW = (1-26) IF PRECEDED BY LAST DIGIT OF CALENDAR YEAR

YE.	AR	Υ	WEEK	W
2011	2001	1	01	A
2012	2002	2	02	В
2013	2003	3	03	С
2014	2004	4	04	D
2015	2005	5		
2016	2006	6		
2017	2007	7		
2018	2008	8	1	1
2019	2009	9	7	7
2020	2010	0	24	X
			25	Υ
			26	Z

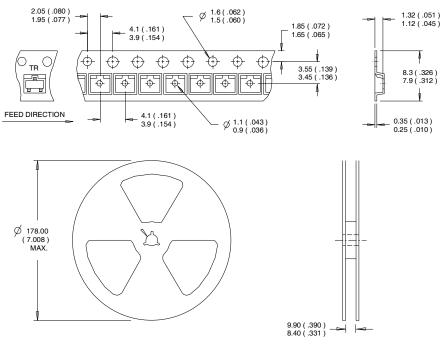
WW = (27-52) IF PRECEDED BY ALETTER

YE	AR	Υ	WORK WEEK	W
2011	2001	Α	27	Α
2012	2002	В	28	В
2013	2003	С	29	С
2014	2004	D	30	D
2015	2005	E		
2016	2006	F		
2017	2007	G		
2018	2008	Н		
2019	2009	J	7	1
2020	2010	K	50	X
			51	Υ
			52	7

Note: For the most current drawing please refer to IR website at: http://www.irf.com/package/

Micro3™ (SOT-23)Tape & Reel Information

Dimensions are shown in millimeters (inches)



NOTES:

CONTROLLING DIMENSION : MILLIMETER.
 OUTLINE CONFORMS TO EIA-481 & EIA-541.

Orderable part number)rdorable part number Backage Type		Pack	Note
Orderable part number	Package Type	Form	Quantity	
IRLML9301TRPbF	Micro3 (SOT-23)	Tape and Reel	3000	

Qualification information[†]

Qualification level	Cans umer ^{††}	
	(per JE DE C JES D47F ^{†††} guidelines)	
Moisture Sensitivity Level	Micro3 (SOT-23)	MS L1
		(per IPC/JEDECJ-STD-020D ^{†††})
RoHS compliant	Yes	

- † Qualification standards can be found at International Rectifier's web site http://www.irf.com/product-info/reliability
- †† Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information: http://www.irf.com/whoto-call/salesrep/
- ††† Applicable version of JEDEC standard at the time of product release.

Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Pulse width $\leq 400\mu s$; duty cycle $\leq 2\%$.
- 3 Surface mounted on 1 in square Cu board
- Refer to application note #AN-994.

Data and specifications subject to change without notice.



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